

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,847,338 B2
DATED : January 25, 2005
INVENTOR(S) : Naoto Abe et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page.

Item [56], **References Cited**, OTHER PUBLICATIONS, "M. Hartwell," reference, "M. Hartwell, IEEE Transactions Electron Devices Conference, 519 (1975); Strong Electron Emission from Patterned Thin-Indium Oxide Thin Films." should read -- M. Hartwell, IEEE Transactions Electron Devices Conference, 519 (1975); Strong Electron Emission from Patterned Tin-Indium Oxide Thin Films. --
FOREIGN PATENT DOCUMENTS
"JP 61-31332 2/1989" should read -- JP 64-31332 2/1989 --.

Column 1.

Line 26, ""Radio" should read -- Radio --.
Line 43, "remission" should read -- emission --.
Line 44, "molybdenium" should read -- molybdenum --.

Column 11.

Line 32, "wring," should read -- wiring --.
Line 47, "other." should read -- other). --.

Column 15.

Line 36, "electron.source" should read -- electron source --.

Signed and Sealed this

Twenty-eighth Day of June, 2005



JON W. DUDAS
Director of the United States Patent and Trademark Office